

BPX 82

Array Linear

Silicon NPN Phototransistor Arrays



Applications

- Industrial Automation (Machine controls, Light barriers, Vision controls)

Features:

- Package: clear epoxy
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Spectral range of sensitivity: (typ) 450 ... 1100 nm
- Multiple-digit array package
- High linearity
- Available in groups

Ordering Information

Type	Photocurrent $V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E_e = 0.5 \text{ mW/cm}^2$ I_{PCE}	Ordering Code
BPX 82	320 ... 1000 μA	Q62702P0021

Only one bin within one packing unit (variation less than 2:1)

Maximum Ratings

$T_A = 25\text{ °C}$

Parameter	Symbol	Values	
Operating temperature	T_{op}	min. max.	-40 °C 80 °C
Storage temperature	T_{stg}	min. max.	-40 °C 80 °C
Collector-emitter voltage	V_{CE}	max.	35 V
Collector current	I_C	max.	50 mA
Collector surge current $\tau \leq 10\text{ }\mu\text{s}$	I_{CS}	max.	200 mA
Emitter-collector voltage	V_{EC}	max.	7 V
Total power dissipation	P_{tot}	max.	90 mW
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	V_{ESD}	max.	2 kV

Characteristics

$T_A = 25\text{ °C}$

Parameter	Symbol		Values
Number of detectors	n		2
Dimension "B" (see drawing)	l	max.	4.9 mm
		min.	4.5 mm
Wavelength of max sensitivity	$\lambda_{S\text{ max}}$	typ.	850 nm
Spectral range of sensitivity	$\lambda_{10\%}$	typ.	450 ... 1100 nm
Chip dimensions	L x W	typ.	0.55 x 0.55 mm x mm
Radiant sensitive area	A	typ.	0.11 mm ²
Half angle	φ	typ.	18 °
Photocurrent $V_{CE} = 5\text{ V}$; Std. Light A; $E_v = 1000\text{ lx}$	I_{PCE}	typ.	1900 μA
Dark current $V_{CE} = 20\text{ V}$; $E = 0$	I_{CE0}	typ.	1 nA
		max.	50 nA
Rise time $I_C = 1\text{ mA}$; $V_{CE} = 5\text{ V}$; $R_L = 1\text{ k}\Omega$	t_r	typ.	6 μs
Fall time $I_C = 1\text{ mA}$; $V_{CE} = 5\text{ V}$; $R_L = 1\text{ k}\Omega$	t_f	typ.	6 μs
Collector-emitter saturation voltage ¹⁾ $I_C = I_{PCE, \text{min}} \times 0.3$; $E_e = 0.5\text{ mW/cm}^2$	$V_{CE\text{sat}}$	typ.	150 mV
Capacitance $V_{CE} = 0\text{ V}$; $f = 1\text{ MHz}$; $E = 0$	C_{CE}	typ.	7.5 pF
Thermal resistance junction ambient real	R_{thJA}	max.	750 K / W

Grouping

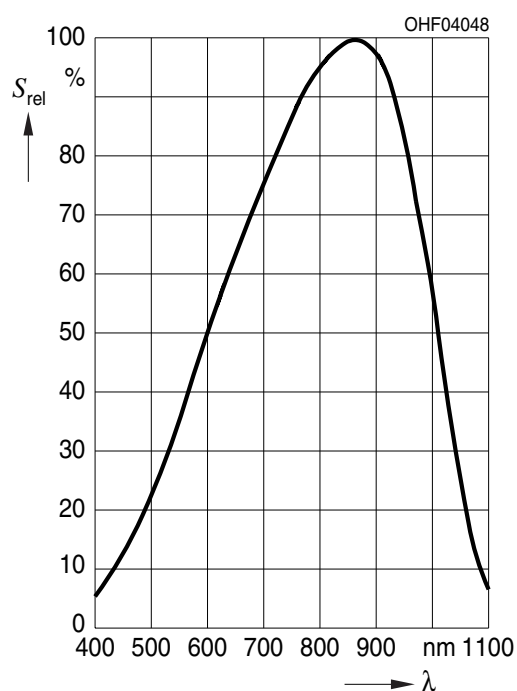
$T_A = 25\text{ °C}$

Group	Photocurrent $V_{CE} = 5\text{ V}; \lambda = 950\text{ nm}; E_e = 0.5\text{ mW/cm}^2$ min. I_{PCE}	Photocurrent $V_{CE} = 5\text{ V}; \lambda = 950\text{ nm}; E_e = 0.5\text{ mW/cm}^2$ max. I_{PCE}
A	320 μA	630 μA
B	400 μA	800 μA
C	500 μA	1000 μA

For delivery the components are marked -A, -B, -C. Due to differing yields it is not possible to order a definite group.

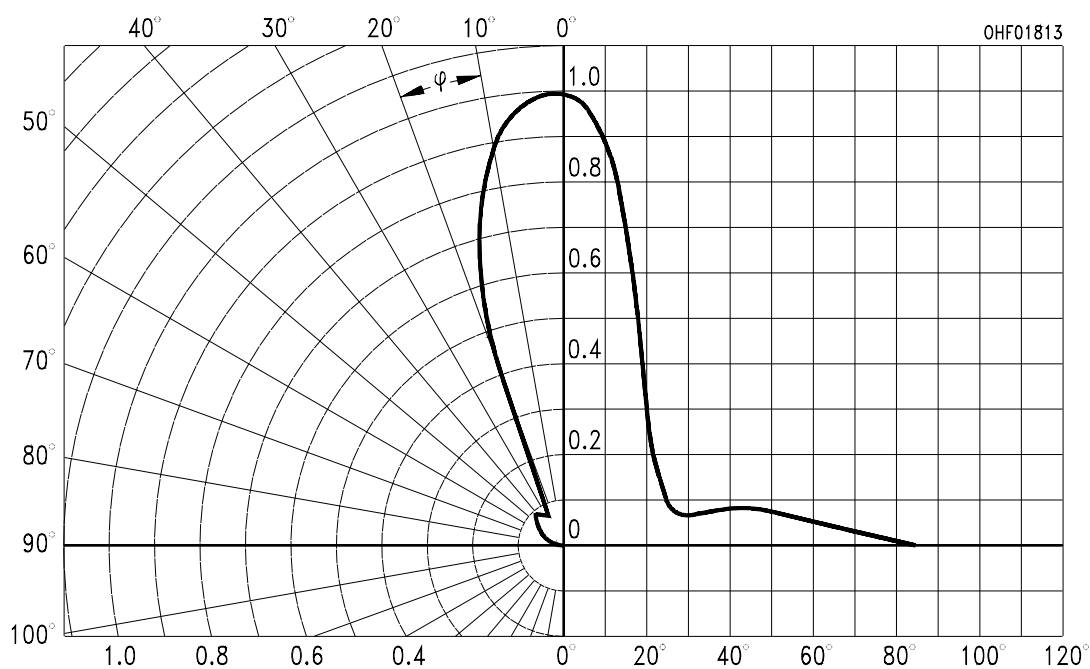
Relative Spectral Sensitivity ^{2), 3)}

$S_{rel} = f(\lambda)$



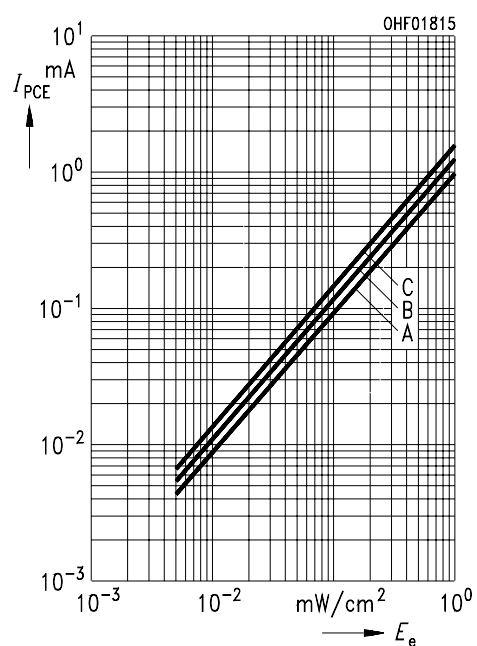
Directional Characteristics ^{2), 3)}

$$S_{\text{rel}} = f(\varphi)$$



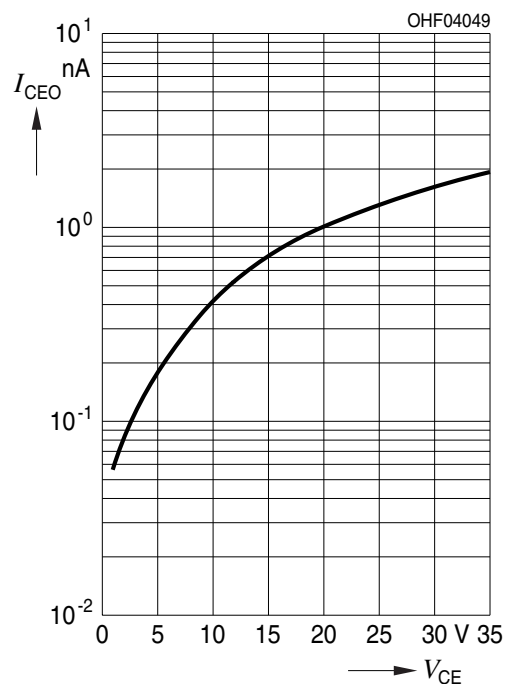
Photocurrent ^{2), 3)}

$$I_{\text{PCE}} = f(E_e) ; V_{\text{CE}} = 5 \text{ V}$$



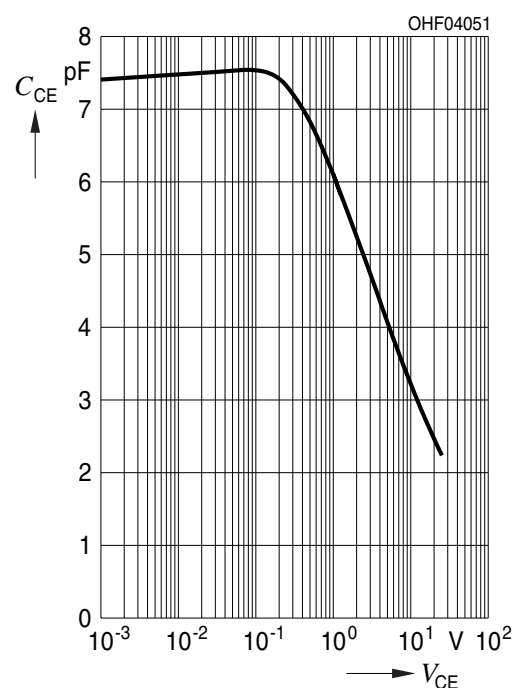
Dark Current ^{2), 3)}

$$I_{\text{CEO}} = f(V_{\text{CE}}) ; E = 0$$



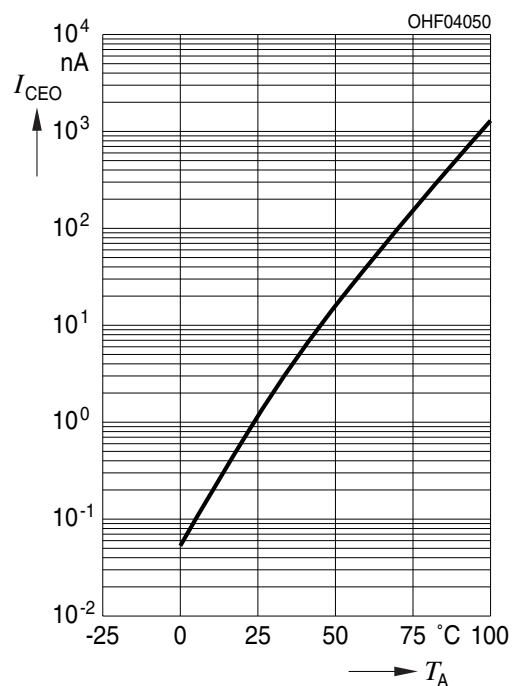
Collector-Emitter Capacitance ^{2), 3)}

$$C_{CE} = f(V_{CE}); f = 1 \text{ MHz}; E = 0;$$



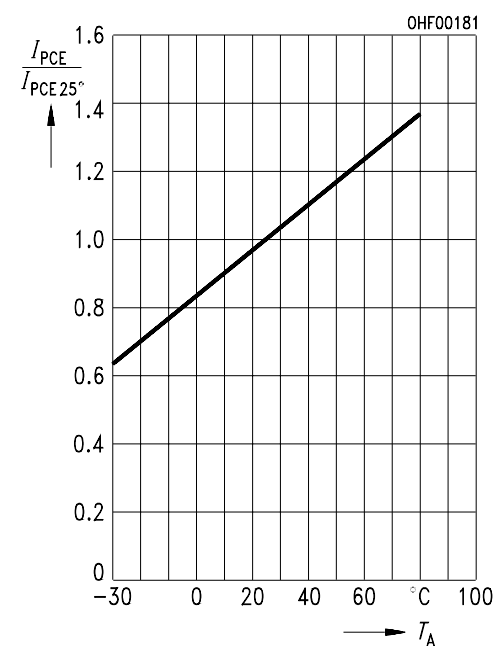
Dark Current ²⁾

$$I_{CE0} = f(T_A); E = 0$$



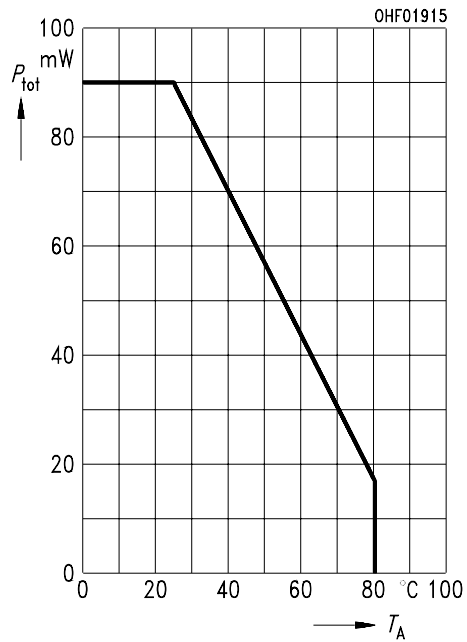
Photocurrent ²⁾

$$I_{PCE,rel} = f(T_A); V_{CE} = 5 \text{ V}$$

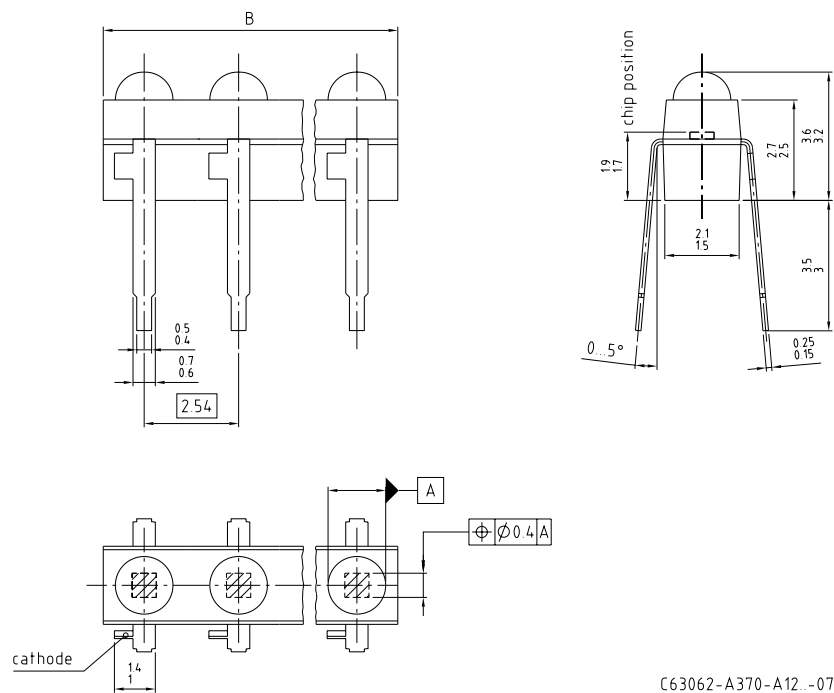


Power Consumption

$$P_{\text{tot}} = f(T_A); R_{\text{thJA}} = 750 \text{ K / W}$$



Dimensional Drawing ⁴⁾

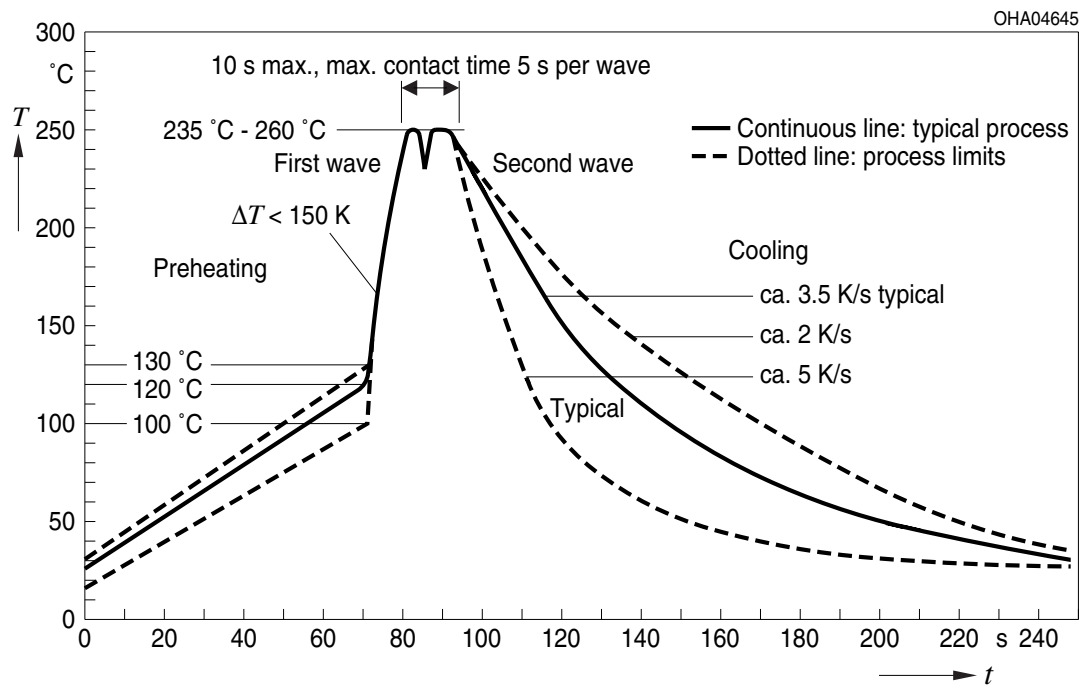


Approximate Weight: 48.0 mg

Package marking: Cathode

TTW Soldering

IEC-61760-1 TTW



Disclaimer

Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the OSRAM OS Website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.

By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

In case Buyer – or Customer supplied by Buyer– considers using OSRAM OS components in product safety devices/applications or medical devices/applications, Buyer and/or Customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and Buyer and /or Customer will analyze and coordinate the customer-specific request between OSRAM OS and Buyer and/or Customer.

Glossary

- 1) **IPCEmin:** I_{PCEmin} is the min. photocurrent of the specified group.
- 2) **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 3) **Testing temperature:** $T_A = 25^\circ\text{C}$
- 4) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ± 0.1 and dimensions are specified in mm.

Published by OSRAM Opto Semiconductors GmbH
Leibnizstraße 4, D-93055 Regensburg
www.osram-os.com © All Rights Reserved.

EU RoHS and China RoHS compliant product



此产品符合欧盟 RoHS 指令的要求；
按照中国的相关法规和标准，不含有毒有害物质或元素。